PNP/NPN Epitaxial Planar Silicon Transistors



## 2SA1405/2SC3599

# Ultrahigh-Definition CRT Display Video Output Applications

## **Applications**

- · Ultrahigh-definition CRT display.
- · Video output.
- · Color TV chroma output.
- · Wide-band amp.

#### **Features**

- $\cdot$  High  $f_T$ :  $f_T$  typ=500MHz.
- · High breakdown voltage: V<sub>CEO</sub>≥120V.
- · Small reverse transfer capacitance and excellent high-frequnecy characteristic
  - : C<sub>re</sub>=2.5pF (NPN), 3.8pF (PNP).
- · Complementary pair with the 2SA1405/2SC3599.
- · Adoption of FBET process.

#### (): 2SA1405

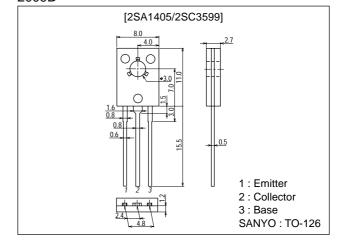
## **Specifications**

### **Absolute Maximum Ratings** at Ta = 25°C

## **Package Dimensions**

unit:mm

2009B



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)120	V
Collector-to-Emitter Voltage	VCEO		(-)120	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)4	V
Collector Current	IC		(-)300	mA
Collector Current (Pulse)	ICP		(-)600	mA
Collector Dissipation	D.		1.2	W
	PC	Tc=25°C	8	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Ullit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)80V, I <sub>E</sub> =0			(-)0.1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)2V, I <sub>C</sub> =0			(-)1.0	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CB</sub> =(-)10V, I <sub>C</sub> =(-)50mA	40*		320*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =250mA	20			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		500		MHz

\* : The 2SA1405/2SC3599 are classified by 50mA h<sub>FE</sub> as follows :

 Rank
 C
 D
 E
 F

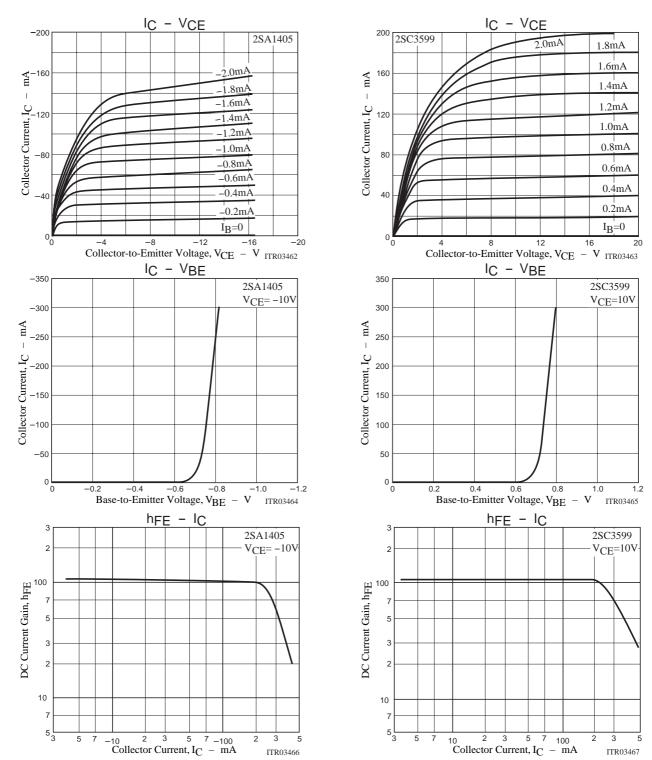
 hFE
 40 to 80
 60 to 120
 100 to 200
 160 to 320

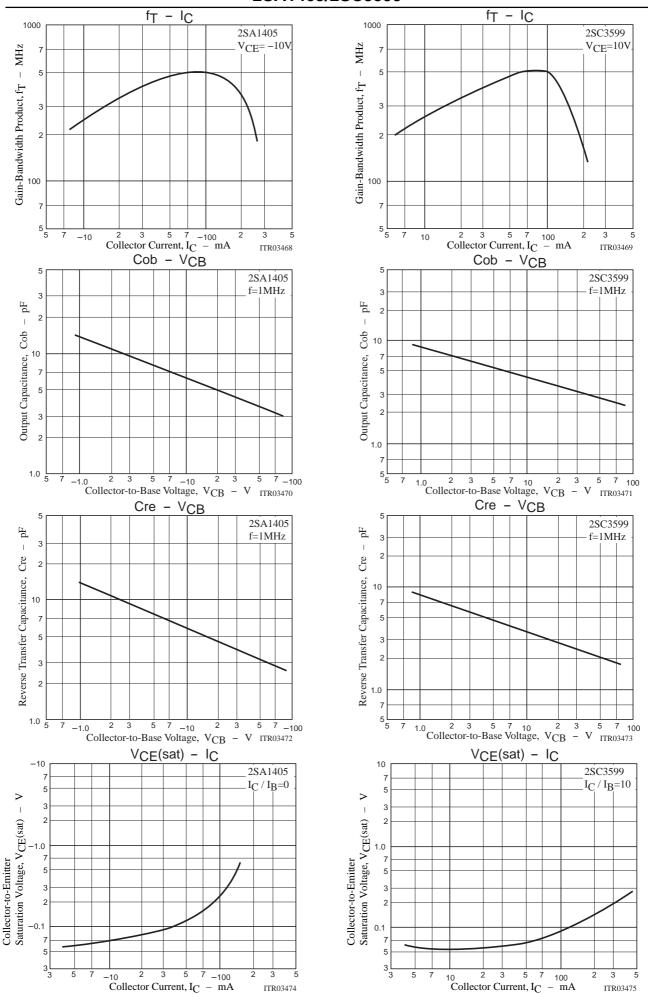
- Continued on next page.
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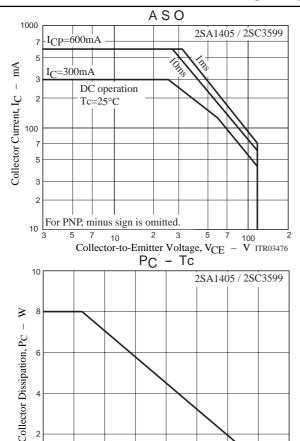
#### Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)70mA, I <sub>B</sub> =(-)7mA			0.6	V
					(–)0.8	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)70mA, I <sub>B</sub> =(-)7mA			(–)1.0	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(–)120			٧
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=(-)1mA, R <sub>BE</sub> =∞	(–)120			V
Emitter-to-Base Breakdown Votage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)100μA, I <sub>C</sub> =0	(-)4			V
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		2.9		pF
				(4.3)		pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		2.5		pF
				(3.8)		pF





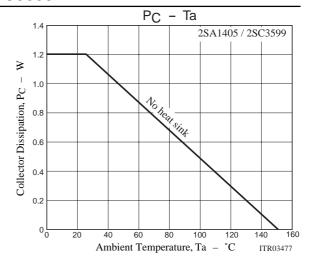
## 2SA1405/2SC3599



Case Temperature, Tc - °C

0 0

20



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